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An in situ kinetic study of brass dezincification and corrosion

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ABSTRACT

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The kinetics of the anodic dissolution of brass (CuZn42 and CuZn21Si3P) in synthetic tap water were investigated by atomic emission spectroelectrochemistry. Elemental Cu and Zn dissolution rates were measured *in situ* and in real time during galvanostatic dissolution. A complete mass/charge balance for the system yielded, as a function of applied current and a function of time, the quantity of Cu in the dezincification layer and the quantity of Cu and Zn in the oxide layer. In this way, a complete kinetic characterization of the fundamental chemical processes occurring during dezincification was realized for the first time. The oxide layer was composed primarily of Cu₂O as indicated by grazing incidence XRD and Raman analysis. The soluble Cu oxidation product was determined to be Cu(II) by a mass/charge balance. Zn was oxidized to soluble Zn(II) leaving behind a trivial amount of solid Zn corrosion product on the surface. The kinetic analysis depicts a two-stage dissolution process of dezincified layer was much slower. The Cu₂O layer grows continually during the exposure.

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1. Introduction

The corrosion process of brass often involves a mechanism of dezincification in which Zn is selectively dissolved leaving behind a porous metallic Cu enriched layer. Dezincificaiton is a major limiting factor for the use of brass in numerous applications and is also a model system for the selective dissolution of a binary alloy. It is not surprising that much attention has been paid to the mechanistic explanation of dezincification [1–14] and the characterization of the dezincification structure [15-18]. Numerous theories have been proposed which may ultimately be categorized into two groups: a mechanism of selective dissolution and a mechanism of dissolution-redeposition. Selective dissoluion theories such as volume diffusion of Zn [13] and/or Cu [14], surface diffusion [19], sometimes in conjunction with divacancy movement [4,7–10,20], as well as the percolation mechanism [21], are most representative. They depict a selective dissolution process of Zn without the electrochemical involvement of atomic Cu. The dissolution-redeposition of Cu [2,5,10,11], however, describes an simultaneous dissolution of both Cu and Zn, followed by a process of Cu plating back onto the surface, thus forming a defective metallic Cu layer.

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http://dx.doi.org/10.1016/j.electacta.2017.01.078 0013-4686/© 2017 Elsevier Ltd. All rights reserved. A difficulty in identifying the underlying mechanisms of brass corrosion has been the fact that the oxidation of the brass, frequently measured as an anodic current in an electrochemical experiment, usually involves at least two different elements and results in both soluble and insoluble species. Various methods have been proposed to measure the partial dissolution rates of Zn and Cu. Intermittent chemical analysis of Cu and Zn in the electrolyte was used by Pickering et al. [6–9], and the radioactive emissions of isotopes of Zn and Cu were followed by Polunin [10] and Pchelnikov et al. [21]. However, these methodologies have various drawbacks: intermittent electrolyte analysis neglects important transitional concentration changes, and the irradiation effect of radioactive indicators may cause the radiolysis of the electrolyte, thus affecting the corrosion process [22] and in any case, is only applicable to special alloys produced with isotopic Cu and Zn.

Another problem is the complex nature of the oxide and zinc depleted metallic layers that are formed during corrosion. Most academic research of dezincification has been performed in acidic media where no oxide is formed [3,23,24]. However, the nearly neutral pH of tap water leads to a more complicated corrosion process and more severe dezincification [25] despite the lower corrosion rate. This dezincification severity and complexity is due to the formation of a multi-layered dezincification structure consisting of a Zn depleted layer and a corrosion product layer composed of Zn and Cu oxides [15,16].

Nomenclature	
LOD	limit of detection for a specific element $(\mu g m L^{-1})$
STW	synthetic tap water
CBS	citrate buffer solution
A	reaction area of the sample (cm ²)
f	flow rate (mL s^{-1})
i _{ap}	applied current during anodization ex-
up	periment (nA cm ⁻²)
Ε	potential (V vs. SCE)
t	time (s)
F	Faradaic constant (=96500C mol ^{-1})
τ	empirical parameter for log-normal fit (s)
β	empirical parameter for log-normal fit
	(no unit)
Ve	applied current expressed as transfer rate
	of electrons (nmol s ^{-1} cm ^{-2})
ν_e^*	v_e convoluted (nmol s ⁻¹ cm ⁻²)
n	stoichiometry factor of Cu (no unit)
$\nu_{Zn(aq)}$	dissolution rate of soluble Zn species
	$(nmol s^{-1} cm^{-2})$
$\nu_{Cu(aq)}$	dissolution rate of soluble Cu species
_	$(nmol s^{-1} cm^{-2})$
$\nu\Sigma$	sum of dissolution rate of soluble Cu and
	$Zn (nmol s^{-1} cm^{-2})$
$Q_e(pstat)$	the quantity of electricity obtained by
	integrating the current transient (nmol
a (1973)	cm ⁻²)
Q_e (ICP)	the quantity of electricity obtained by
	calculating the electrochemical reaction
	assuming a known reaction factor (nmol
	cm ⁻²) stoichiometry factor of aqueous species
n _{m,aq}	for Cu, Zn or Si (no unit)
	stoichiometry factor of solid species for
n _{m s}	Cu, Zn or Si (no unit)
Q _{m.an}	the quantity of elemental dissolution of a
∠ m,an	metal, <i>m</i> (Cu, Zn and Si), contributed to
	either aqueous species (<i>aq</i>) or solid
	species (s) (nmol cm ⁻²)
O_m (STW) ($i_{an}=0$)	total quantity of elemental dissolution
	during open circuit exposure in STW
	$(nmol cm^{-2})$
Q_m (CBS) $(i_{ap} = 0)$	total quantity of elemental dissolution in
	CBS following open circuit exposure in
	STW (nmol cm $^{-2}$)
Q_m (STW)	total quantity of elemental dissolution in
	STW during anodization (nmol cm ⁻²)
Q_m (CBS)	total quantity of elemental dissolution in
	CBS during anodization (nmol cm ⁻²)
δ_{Cu}	thickness of dezincified layer (nm)
δ_{Cu_2O}	thickness of oxide layer (nm)
M _{Cu}	atomic weight of Cu $(g mol^{-1})$
ρ _{Cu}	density of Cu $(8.90 \mathrm{g cm^{-3}})$
M_{Cu_2O}	atomic weight of $Cu_2O(gmol^{-1})$
ρ_{Cu_2O}	density of Cu_2O (6.04 g cm ⁻³)
α	the molar ratio of Cu/Zn in the bulk
$\sum v_{m(aq)}$	the sum of elemental dissolution rates $(1 + 1)^{-1} = (1 + 1)^{-2}$
7	$(\text{nmol s}^{-1} \text{ cm}^{-2})$
Z	dezincification factor.
$\mathcal{V}_{Cu(aq)}$	dissolution rate of Cu into aqueous $(nmol s^{-1} cm^{-2})$
	species (nmol s ^{-1} cm ^{-2})

vcorr	open circuit dissolution rate of Cu (nmol s^{-1} cm ⁻²)
v_{Cu_2O}	growth rate of residual oxide film on alloy surface (nmol s ⁻¹ cm ⁻²)
$ u_{Cu}$	growth rate of dezincified layer on alloy surface $(nmol s^{-1} cm^{-2})$

Conventional electrochemical methods such as potentiodynamic polarization [15,26] and electrochemical impedance spectroscopy (EIS) [15,26,27] have been used to predict the corrosion rate and to characterize the electrical properties of the interfacial structure. *In situ* techniques such as Raman spectroscopy [28], infrared reflection absorption spectroscopy (IRAS) [17], near normal incidence reflectance spectroelectrochemical technique (NNIRS) [29] and ultraviolet-visible (UV-vis) reflectance spectroscopy [16] can be used to observe the molecular identity of the oxide. But no quantitative kinetic information about Cu release into water, the growth of oxide layers, or the growth of the zinc depleted layer, has been obtained through these methods.

In this work the kinetics of dezincification are quantified using the atomic emission spectroelectrochemical (AESEC) methodology [31,32]. This technique permits us to measure directly the rates of Cu and Zn dissolution *in situ* and in real time, and indirectly the rate of oxide and metallic Cu film formation. In a previous publication [30], we established the feasibility of using *in situ* AESEC [31,32] to analyze copper dissolution in synthetic tap water in which a detailed quantitative relationship between the soluble Cu(II) ions and the insoluble Cu₂O film was obtained as a function of applied current. In this paper these previous studies are extended to the anodic dissolution of two commercial plumbing brasses in synthetic tap water.

The kinetic methods are demonstrated using two types of commercial brass: A conventional dual α , β' phase low-leaded CuZn42 alloy that is fairly sensitive to dezincification, and a leadfree CuZn21Si3P which is considered to be much more resistant. These commercial plumbing alloys are largely utilized in North America, Europe and Asia. The microstructure of CuZn42 is characterized by an even distribution of α (Cu₃Zn) phase within the β' (CuZn) phase matrix [33,34]; the microstructure of CuZn21Si3P shows about 60% of α phase with some silicon-rich kappa (κ , Cu₈Zn₂Si [35]) phase and gamma (γ , Cu₄ZnSi) phase dispersed within the matrix and the boundary respectively [36]. The corrosion performance of the two alloys had not yet been thoroughly investigated. It is well known that CuZn42 is sensitive to dezincification, as it contains a large amount of the Zn rich β' phase. CuZn21Si3P is a new Pb-free alloy that shows an excellent dezincification resistance. It forms a complex triple-phase structure due to the addition of Si and P. Seuss et al. [1] investigated the corrosion resistance of CuZn21Si3P in aggressive tap water and found that dezincification initiates from these electronegative κ and γ phases, and is then inhibited by a "phosphorous cycle". However, no further information regarding the dissolution kinetics and the mechanism have been provided.

2. Experimental

2.1. Materials

Brass discs of low-leaded CuZn42 and lead-free CuZn21Si3P of $\Phi~24\,mm\times2\,mm~$ were used in this work. Their elemental composition can be found in Table 1. Unless otherwise specified, samples for electrochemical experiments were dry ground up to P1200 (600 grit) silicon carbonate paper, rinsed with deionized water (0.0549 $\mu S\,cm^{-1}~$ at 25 °C) using a MilliporeTM system),

Table 1Compositions of brass samples.

Alloy	Cu	Si	Р	Zn	Pb	Fe	Ni	Sn	Al	Mn
CuZn42 CuZn21Si3P		<0.01 3.06								

degreased with acetone, ethanol, and then dried under flowing nitrogen.

Synthetic tap water (STW) [37] containing MgSO₄·7H₂O (31.92 mg L⁻¹), NaHCO₃ (36.00 mg L⁻¹), CaCl₂·7H₂O (102.9 mg L⁻¹), Na₂SO₄ (275.5 mg L⁻¹), was prepared utilizing deionized water, with a pH of 7.5 ± 0.1 and a conductivity of 479 μ S cm⁻¹. Citrate buffer solution (CBS) was used to dissolve the solid corrosion products formed during dissolution in STW, it was prepared by adjusting the pH value of 0.1 M citrate acid (AppliChem) solution to 4.9 ± 0.1, using 0.1 M citrate trisodium solution (Amresco), and deaerated for at least 30 min with an argon bubbling system before use.

2.2. Dezincification test

The ISO 6509 dezincification test [38,39] was performed in a 12.7 g L⁻¹ CuCl₂ solution, with the sample being exposed to the electrolyte for 24 hours at 75 ± 3 °C and then observed under optical microscope to measure the dezincification depth.

2.3. Instrumentation

The atomic emission spectroelectrochemistry (AESEC) technique was used to follow elemental dissolution kinetics during the corrosion and electrochemical polarization of brass. Details of this technique can be found in previous publications [31,32,40]. Cu dissolution was followed using a monochromator to detect the atomic Cu emission intensity at 324.75 nm. Zn and Si were followed using a polychromator detecting the atomic emission intensity at 213.68 nm and 251.61 nm respectively. A conventional three-standard calibration was conducted for each element. The detection limit (LOD) was defined as three times the standard deviation of background noise divided by the sensitivity (α), which can be determined from the intensity – concentration calibration line. The LOD for Cu in STW and CBS was less than 1 ppb, for Zn it was 6 ppb and for Si it was 17 ppb. A Gamry Reference 600TM potentiostat was used to control and/or measure the current and potential. The analog output of the potentiostat was routed into the data acquisition system of the ICP spectrometer so that spectroscopic intensity and electrochemical data were on an identical time scale.

A two compartment flow cell was used in this work with a reaction area of $A = 1.0 \text{ cm}^2$, and a flow rate $f = 3.0 \text{ mL min}^{-1}$. Details of the cell can be found elsewhere [31,32]. A platinum foil with an area of 5.0 cm² was used as a counter electrode and a saturated calomel electrode (SCE) was used as reference electrode.

A PANalytical X'Pert X-ray Diffractometer using a Cu target (K α = 1.54 Å) was used to analyze the sample following anodization at 80 $\mu A \, cm^{-2}$ in STW. Grazing incidence X-ray diffraction (GIXRD) with an incidence angle (ω) of 0.5° was performed on the oxidized sample. Bulk sample X-ray diffraction (XRD) was performed on a spinning stage.

A Renishaw InVia Raman microscope equipped with a Renishaw CCD camera detector was used to characterize the oxide composition: An Ar ion laser was used with and excitation line at 514 nm focused through a 50×0.75 NA objective, in conjunction with a grating of 1800 g/mm. Reference Cu₂O spectra were obtained by analyzing the Cu₂O powder (Sigma Aldrich).

A Zeiss Leo 1530 field emission scanning electron microscope (FE-SEM) was used to observe the surface morphology of brass samples after being exposed to STW. An in lens second electron detector was used to capture the image; the extra high tension (EHT) was fixed at 5 kV.

2.4. Electrochemical experiments and data analysis

Anodic polarization of brass samples was conducted in STW at an applied current (i_{ap}) ranging from 0 to 80 μ A cm^{-2} for 1200 s, or with a time duration (t) of 0 s, 300 s, 600 s, 1200 s respectively at i_{ap} = 40 μ A cm^{-2} . Before and after the polarization, a 300 s open circuit delay was also imposed respectively. After that, STW was replaced by CBS for a further open circuit dissolution of 1500 s, aiming at dissolving the residual solid corrosion products on the surface.

A detailed description of the data analysis, including the conversion of the emission intensity profile into dissolution rate profile and the convolution of applied current, was given in a previous publication [30].

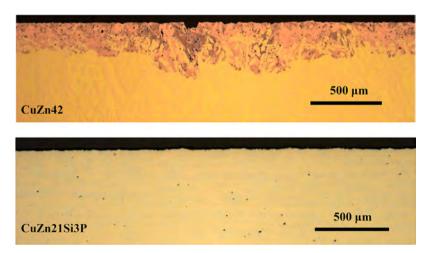


Fig. 1. Optical microscope observation of the dezincification structure of CuZn42 (upper) and CuZn21Si3P (lower) following an ISO 6509 dezincification test. The red defectrich structure on the cross section is the dezincification structure.

3. Results

3.1. Dezincification test result

The ISO6509 accelerated corrosion test confirmed that the CuZn21Si3P was significantly less sensitive to dezincification as compared to CuZn42, Fig. 1. In the micrographs of Fig. 1A, the β ' phase of CuZn42 shows a preferential dezincification as compared to the α matrix, with the dezincification front penetrating along the dezincified β ' phase. As expected, the test of CuZn21Si3P (Fig. 1B) shows a better dezincification performance under

identical test conditions, with an undetectable dezincification structure visible at the magnification of Fig. 1.

3.2. Elemental dissolution behavior in synthetic tap water (STW)

The differences in dezincification kinetics of the two alloys, exemplified by Fig. 1, is also apparent in the transient elemental dissolution rates during accelerated dezincification tests in synthetic tap water (Fig. 2). A typical full experiment is given in Fig. 2 for CuZn42 (A) and CuZn21Si3P (B) respectively. The experiment is divided into four stages: (a) an open circuit

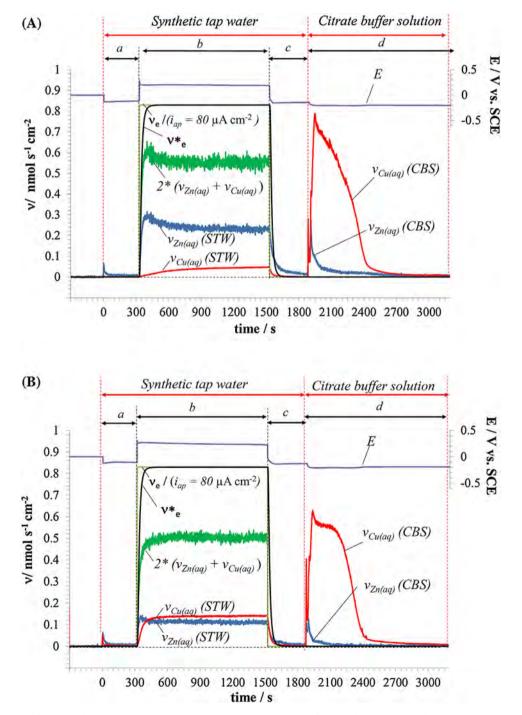


Fig. 2. STW-CBS experiment of CuZn42 (A) and CuZn21Si3P (B) at *i*_{ap} = 80 μA. a: open circuit in STW for 300 s; b: galvanostatic dissolution in STW at 80 μA for 1200 s; c: open circuit in STW for 300 s; d: open circuit in CBS for 1500 s.

dissolution in STW for 300 s; (b) a galvanostatic pulse for 1200 s; (c) another open circuit dissolution for 300 s; and finally, (d) dissolution of residual oxide films formed during (a - c) by exposure to CBS at open circuit dissolution for 1500 s. Prior to t = 0 s, the pure electrolyte was fed into the plasma permitting a measurement of the background intensity and detection limit for each element. These experiments were performed with either an applied anodic galvanostatic current ranging from 0 to 80 $\mu A cm^{-2}$ for 1200 s, or a time duration ranging from 0 to 1200 s at 40 $\mu A cm^{-2}$.

The Cu and Zn dissolution rates, $(\nu_{Zn(aq)}, \nu_{Cu(aq)})$ and the electron transfer rate, ν_{e} , are given as a function of time in Fig. 2. This type of presentation will be referred to as a *dissolution profile*. Also shown is the electron transfer rate convoluted with the hydrodynamic distribution of time constants in the flow cell, ν_{e}^{*} . This corrects for the different time resolution between the electrochemical data which are essentially instantaneous, and the elemental dissolution rates which are broadened by mixing in the cell, capillaries, and nebulization system [42]. Also presented is the sum of the elemental dissolution, $\nu_{\Sigma} = \nu_{Zn(aq)} + \nu_{Cu(aq)}$. This data set has been multiplied by a factor of 2 to facilitate comparison with ν_{e}^{*} (see below.) Si dissolution was also detected, but it is not shown due to a poor signal to noise ratio.

The open circuit dissolution rates of Zn and Cu in STW were readily measured for both alloys, although it is not apparent on the scale of Fig. 2. An enlarged view of the open circuit dissolution STW is shown in Fig. 3A and 3B. The average open circuit dissolution

Table 2

Steady dissolution rate of brass alloys in STW (upper) and deaerated CBS (lower).

		$\frac{Zn}{pmol s^{-1}}$	$\frac{Cu}{pmol s^{-1}}$	Cu (congruent)
STW CBS	CuZn42 CuZn21Si3P CuZn42 reference CuZn42 CuZn21Si3P reference CuZn21Si3P	$\begin{array}{c} 9.59 \pm 5.22 \\ 5.22 \pm 1.02 \\ 1.82 \pm 2.11 \\ 3.28 \pm 1.68 \\ 1.39 \pm 1.83 \\ 1.65 \pm 0.69 \end{array}$	$\begin{array}{c} 0.60 \pm 0.85 \\ 1.67 \pm 1.11 \\ 2.32 \pm 0.78 \\ 5.40 \pm 0.78 \\ 3.13 \pm 0.92 \\ 6.98 \pm 1.28 \end{array}$	13.43 18.84 2.55 4.59 5.13 6.09

rates for each alloy in STW (stage *a*) are listed in Table 2. Also listed in the table are the theoretical congruent dissolution rates of Cu and Si in STW and CBS, with reference to the experimental Zn partial corrosion rate, based on the component ratio of the bulk. For both alloys in STW (Table 2), the Cu partial corrosion rate is significantly lower than the congruent value calculated from the Zn dissolution rate. This rate discrepancy is indicative of a selective Zn dissolution process leaving behind either an oxidized Cu film or a metallic Cu layer.

It is of interest to compare this Zn selective leaching with that observed in the CBS electrolyte directly at the end of the experiment, (stage d in Fig. 2). This data is also given in Table 2. In this case, the Cu dissolution rate was equivalent to or slightly higher than the estimated congruent dissolution rate indicating that Cu corrosion products were soluble in this electrolyte.

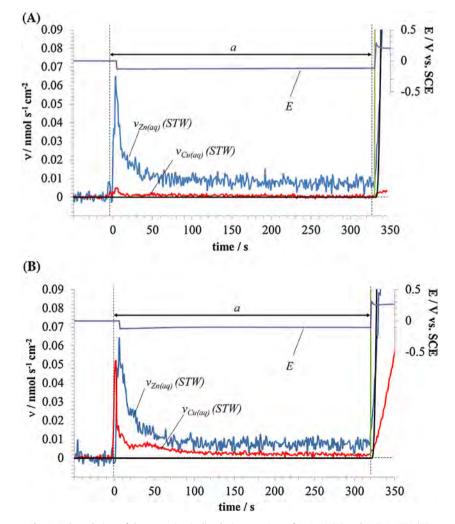


Fig. 3. Enlarged view of the open circuit dissolution transient of CuZn42 (A) and CuZn21Si3P (B).

Insight into the formation of oxide films during the galvanostatic pulse may be derived from a quantitative consideration of the dissolution rates as compared to the electron transfer rate during the anodic stage b of Fig. 2. The sum of the elemental dissolution rates is well below the electron exchange rate, v_e , even when the former is multiplied by 2, the highest valence that one would reasonably expect for either Cu or Zn in this electrolyte. The difference between the oxidative electron transfer and elemental dissolution may be explained by the formation of insoluble oxidized Cu and/or Zn species since no other significant oxidation reactions would be expected in this electrolyte at the potentials used.

Fig. 4 shows the superimposition of Cu and Zn dissolution at various galvanostatic currents. A remarkable feature of the Zn dissolution profiles shown in this figure is the transient response to the anodic polarization, leading to a rapid increase in the Zn dissolution rate, which decreased gradually throughout the remainder of the anodic pulse. This curious behavior coincides

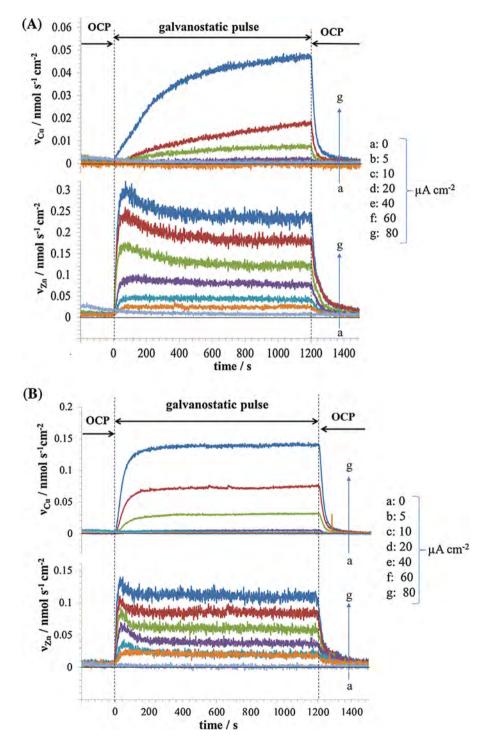


Fig. 4. Elemental dissolution of CuZn42 (A) and CuZn21Si3P (B) in exposure to STW. Upper: dissolution of Cu; lower: dissolution curve of Zn. Curves from upper to lower in μ A cm⁻²: 80, 60, 40, 20, 10, 5, 0.

with the results observed by Pchelnikov [11] using Zn isotopes and Pickering [6] using quantitative chemical analysis of the electrolyte. The Cu dissolution rate, however, increased gradually, though at different rates for different alloys: for CuZn42, a sluggish increase of Cu dissolution rate was observed with no steady state till the end of the 1200 s anodic period. In contrast, for CuZn21Si3P, a steady state dissolution rate was reached after about 300 s after the initiation of anodic polarization. This was followed by a rapid decrease (stage c), identical for both alloys. Also, for CuZn42, during the first few seconds of the anodization, no soluble Cu

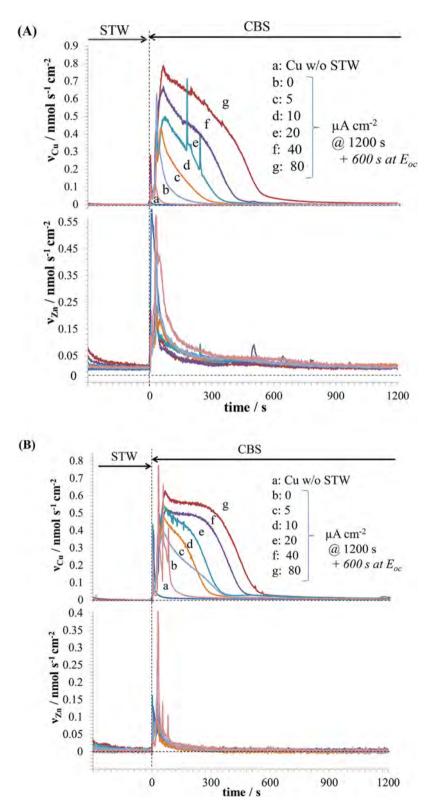


Fig. 5. Superimposition of residual film dissolution of CuZn42 (A) and CuZn21Si3P (B) in CBS. Captions a - g: a: fresh brass exposed to CBS; b - g represents $i_{ap}/\mu A$ cm⁻² = 0, 5, 10, 20, 40 and 80 respectively.

species were detected, while Zn dissolution increased rapidly. This period will be referred to as an induction period. The induction period was not observed on CuZn21Si3P.

3.3. Analysis of insoluble corrosion products

The formation of insoluble corrosion products during the galvanostatic pulse was clearly demonstrated by the significant mismatch between the sum of the elemental dissolution rates and the electrical current (stage b in Fig. 2. The feasibility of using CBS to dissolve insoluble copper corrosion products with minimal corrosion of the substrate was previously demonstrated [30]. In this paper, the same methodology was used. Dissolution profiles of the corrosion products in deaerated CBS electrolyte are given in Fig. 5. The integral of the Cu and Zn dissolution transients in Fig. 5, gives the total amount of each element in the corrosion product film present at the surface following the exposure to STW, referred to as $Q_{Cu}(CBS)$ and $Q_{Zn}(CBS)$. It is clear from the figure that the corrosion product layer was mainly composed of Cu oxides [46], with Zn oxide and/or hydroxides as a minor constituent. The value of Q_{Zn}(CBS) showed no statistically significant variation in quantity with either galvanostatic time or current [45,46].

To further verify that the dissolution waves of Cu and Zn were from the dissolution of the oxides rather than the dissolution of the substrate, a reference experiment was conducted with a fresh brass sample in deaerated CBS, curve *a* in Fig. 5. For CuZn42, a large peak of Zn and a negligible peak of Cu were observed when exposed to CBS for a few seconds. For CuZn21Si3P, relatively comparable peaks of Cu and Zn were observed. These peaks were significantly different from the dissolution wave of the alloys after STW exposure, and demonstrate that neither the substrate nor the metallic component of the dezincification layer contribute significantly to the dissolution profiles of curve *b-g*. Note that the quantity of Cu is negligible in curve a as compared to the other experiments so it is safe to ignore the corrosion of the substrate during the determination of the quantity of residual oxides.

For both CuZn42 and CuZn21Si3P, a salmon colored layer was visually observable after removal of the oxide layer by CBS. This layer corresponded to the Zn depleted metallic Cu layer which was not soluble in CBS. The presence of this metallic Cu film affected the steady state open circuit dissolution rates in CBS (Table 2). For the reference experiments with freshly ground samples (no preexisting oxide layer) both alloys show a slight preferential dissolution of Zn as compared to their bulk composition (curve *a* in Fig. 5). This was much less significant than in STW due no doubt to the solubility of the solid Cu oxidation products. However, when the alloy had been subjected to a galvanostatic treatment, the corrosion rate in CBS after oxide dissolution, yielded a Cu

dissolution rate larger than that predicted for congruent dissolution attributed to the excess Cu content of the material exposed to the electrolyte. Nevertheless, the Zn dissolution rate did not appear to be affected, indicating that the dezincification layer did not significantly protect the underlying substrate from corroding.

3.4. Characterization of residual oxides

The residual oxide film formed on pure Cu in STW was almost entirely composed of Cu₂O as demonstrated in [30]. To verify whether or not this was the case for the brass samples, GIXRD and Raman spectrometry were used to analyze the oxide layer formed after anodic polarization at various applied current for 1200s. Fig. 6 presents the GIXRD results of both alloys with pure Cu as a reference [30]. Consistent with the case of pure Cu, crystallized Cu₂O was detected on both alloys after anodic polarization. However, no peaks corresponding to a pure Cu dezincified layer could be detected by GIXRD as would be evidenced by Cu fcc lattice peaks shifted due to the change in lattice parameter from lack of substitutional Zn, even though the Cu film was visually observable. Similarly, the Raman spectra (Fig. 7) show peaks at $150 \, \text{cm}^{-1}$, $220 \, \text{cm}^{-1}$, $411 \, \text{cm}^{-1}$ and $650 \, \text{cm}^{-1}$ supporting the existence of Cu₂O. Nonetheless, the existence of CuO cannot be excluded since the Raman shift of CuO at 633 cm⁻¹ is very close to that of Cu₂O at 635 cm⁻¹ [41,42,43]. Moreover, it is possible that some thin amorphous CuO species cannot be detected by GIXRD or Raman spectroscopy [43]. The Raman shift at 525 cm⁻¹ was due to Cu-OH vibration in defective Cu₂O [44]. It is thermodynamically possible that some Cu₂O can be further oxidized into CuO by exposure to air. However, since neither GIXRD nor Raman spectroscopy detected any Cu(II) species, it is reasonable to conclude that even if CuO exists at the surface, its quantity is still far smaller than the Cu₂O in the surface oxide film.

3.5. Surface morphology

Based on the previous analysis, it's clear that cuprite (Cu₂O) is the primary solid corrosion product deposited on the surface. The distribution of the corrosion product on the surface was investigated by SEM observations of the brass samples before and after exposure to STW at $i_{ap} = 5 \,\mu\text{A cm}^{-2}$ and $t = 1200 \,\text{s}$ (Figs. 8,9). Note that samples used for SEM observation were polished to 1 μ m diamond paste to a mirror finish. Such a low current was chosen to enable the formation of Cu oxides among different phases after the induction period, as is shown in Fig. 4(A). Further, a larger applied current will produce more oxide film on the surface, thus covering the surface, making it difficult to differentiate the different metallurgical phases. For these samples,

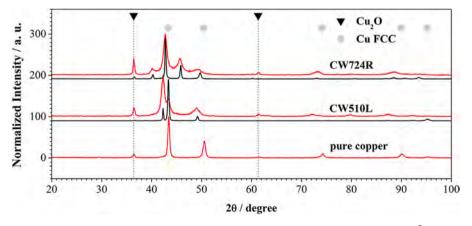


Fig. 6. GIXRD results of CuZn42 and CuZn21Si3P after exposure to STW at i_{ap} = 80 μ A cm⁻².

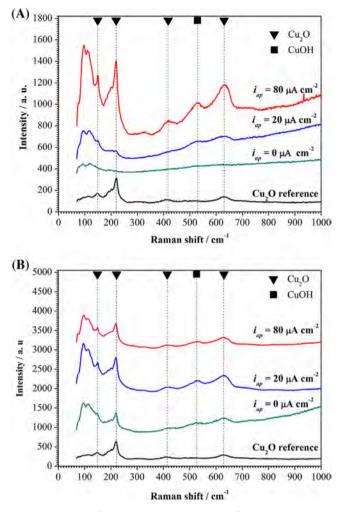


Fig. 7. Raman spectra of CuZn42 (A) and CuZn21Si3P (B) after exposure to synthetic tap water at different anodic current.

the oxide layer of CuZn42 was formed in the center of the reacting zone, and the layer of CuZn21Si3P was evenly distributed on the exposure area. Only the region which shows a complete coverage of oxide film was observed by SEM. Both figures show cubic solid crystalline products distributed on the surface. These cubic-shaped crystals were assumed to be Cu₂O based on GIXRD and Raman analysis. However, the distribution of cubic Cu₂O on the surface is completely different among the two alloys: in Fig. 8, cubic crystals were evenly formed on the surface and no clear sign of preferential deposition of Cu₂O on the different metallographic phase structures was found, with respect to the duplex structure of CuZn42. However, the distribution of Cu₂O on CuZn21Si3P shows a remarkable preferential distribution: in Fig. 9, a clear crystal boundary based on the distribution of Cu₂O can be distinguished. In fact, more than 50% of the area was covered with evenly distributed cubic particles, and the other half showed a lower density of Cu₂O cubic particles with incomplete coverage.

3.6. Mass and Charge Balance

The quantity of the Cu oxide and of the residual metallic Cu layer as a function of time may be determined from a detailed mass/charge balance for the dissolution of Cu and Zn during the STW experiments. This requires knowledge of the oxidation states of the corrosion products. Based on the previous surface characterization, it's reasonable to assume that brass dissolution The validity of these assumptions- that the corrosion products consists of Cu(II) and Zn(II) aqueous and Cu(I) solid species- may be verified by comparing the total quantity of electricity, $Q_e(pstat)$ during the galvanostatic pulse, with the total equivalent electricity from the calculated from the elemental dissolution rates, $Q_e(ICP)$.

$$Q_e(ICP) = \sum n_{m,aq} Q_{m,an(aq)} + \sum n_{m,s} Q_{m,an(s)}$$
(1)

where $Q_{m,an}$ represents the quantity of elemental dissolution of a metal, m (Cu, Zn and Si), contributed to either aqueous species (aq) or solid species (s), and $n_{m,aq}$, $n_{m,s}$ are the valence of each species in the form of aqueous or solid state. The two terms on the right of eq. 1, $Q_{m,an(aq)}$ and $Q_{m,an(s)}$, are the net quantity of aqueous and solid species attributed to the galvanostatic pulse, which can be further calculated through eq. 2-3.

$$Q_{m,an(aq)} = Q_m (STW) - Q_m (STW)(i_{ap} = 0)$$
⁽²⁾

$$Q_{m,an(s)} = Q_m (CBS) - Q_m (CBS) (i_{ap} = 0)$$
 (3)

where $Q_m(STW)$ and $Q_m(CBS)$ correspond to the total quantities of elemental dissolution of *m* during the STW or CBS period. These values are determined by integration of the dissolution profiles. The quantity of elemental species formed during the open circuit exposure must be removed from this value in order to obtain the correct mass balance. In equation 2 & 3 this background mass was assumed to be given by $Q_m(STW)(i_{ap} = 0)$ and $Q_m(CBS)(i_{ap} = 0)$, the quantity of aqueous species of element *m* in STW, when $i_{ap} = 0$. The subtraction of these terms from $Q_m(STW)$ and $Q_m(CBS)$ provides a net quantity of each species produced by the galvanostatic current, since all the experiments were performed on an identical time scale.

The comparison between $Q_e(ICP)$ and $Q_e(pstat)$ at various applied current or various time duration was shown in Fig. 10A and B. The experimental data fits the $Q_e(ICP) = Q_e(pstat)$ (dashed line) fairly well within experimental error, though some deviation is observed at higher current, which may be due to the errors in background subtraction discussed above, or perhaps the existence of a trace amount of solid Cu(II) species. Nevertheless, the relatively good agreement of experimental points with the $Q_e(ICP) = Q_e(pstat)$ line corroborates the assumption of the oxidization state of each element in the aqueous and the solid phase.

3.7. Growth of the dezincification and the oxide layers

It is of great mechanistic interest to investigate the rates of formation of aqueous Cu^{2+} , the solid Cu_2O corrosion product layer, and the Zn depleted metallic copper layer as a function of applied current or time. Fig. 11 gives the values of $Q_{Cu}(STW)$ representing the quantity of Cu dissolved, and $Q_{Cu}(CBS)$ representing the quantity of solid Cu_2O oxide formed, plotted as a function of applied current for both alloys. In all cases the Cu_2O formation is clearly favored over Cu^{2+} dissolution, as was observed for pure Cu dissolution under identical experimental conditions [30]. Also, the growth rate of Cu_2O oxide film on both alloys decreased with the

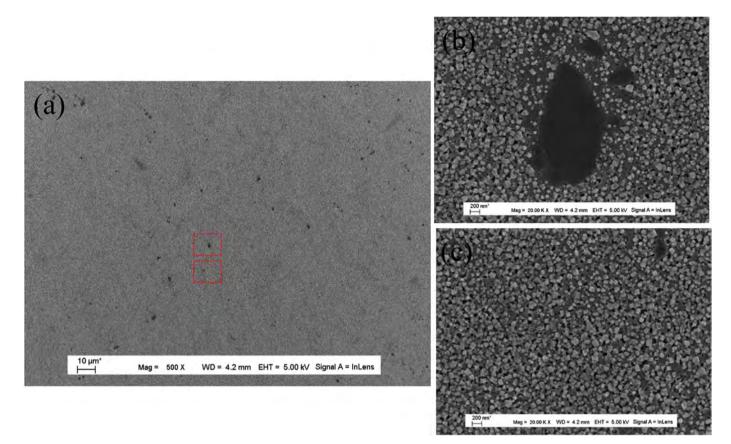


Fig. 8. SEM observation of the surface topography of CuZn42 being anodically polarized in STW. i_{ap} = 5 μ A cm⁻², t = 1200 s.

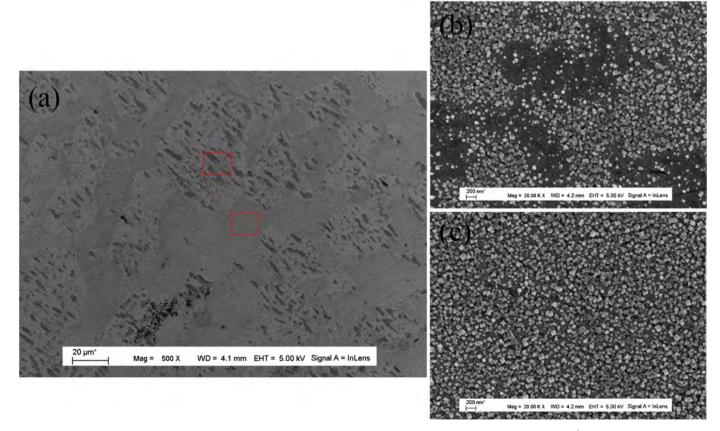


Fig. 9. SEM observation of the surface topography of CuZn21Si3P being anodically polarized in STW. i_{ap} = 5 μ A cm⁻², t = 1200 s.

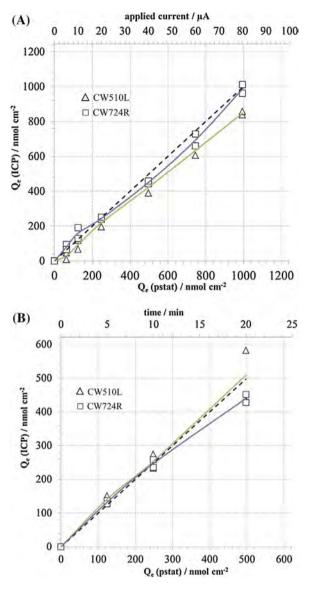


Fig. 10. Comparison between Q_e (pstat) and Q_e (ICP) for CuZn42 (\triangle) and CuZn21Si3P (\Box) respectively as a function of applied current (A) and as a function of time duration (B).

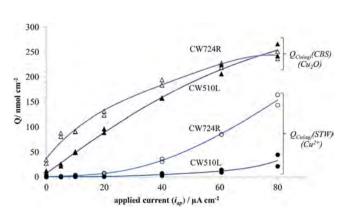


Fig. 11. The increase of soluble species $(Q_{Cu(aq)}(STW))$ and insoluble species $(Q_{Cu}_{(aq)}(CBS))$ as a function of applied current for CuZn42 and CuZn21Si3P.

increase of i_{ap} , while the growth rate of Cu²⁺ began to increase at higher current.

The establishment of mass/charge balance calculation allows us to estimate the thickness of the dezincified layer, assuming a compact pure Cu layer sandwiched by the outermost Cu₂O layer and the brass substrate. The thickness of the dezincified layer (δ_{Cu}) and residual oxide film (δ_{Cu2O}) can be estimated through eq. 4-5:

$$\delta_{Cu} = \frac{M_{Cu}\{\alpha[Q_{Zn}(STW) + Q_{Zn}(CBS)] - [Q_{Cu}(STW) + Q_{Cu}(CBS)]\}}{\rho_{Cu}}$$
(4)

$$\delta_{Cu20} = M_{Cu20} \frac{Q_{Cu(aq)}(CBS)}{Cu20}$$
(5)

where α represents the molar ratio of Cu/Zn in the bulk; ρ_{Cu} and ρ_{Cu20} are the density of each component assuming that the dezincified layer and the corrosion product layer are both compact and dense; M_{Cu} and M_{Cu20} are the molar mass for each component. The growth of δ_{Cu} and δ_{Cu20} as a function of the applied current are presented in Fig. 12 assuming a ρ_{Cu} = 8.90 g cm⁻³ and ρ_{Cu20} = 6.04 g cm⁻³. This calculation definitely underestimates the thickness of the pure Cu layer and the Cu₂O layer, considering the porous structures of both. However, the growth of both layers with the increase of applied current signifies that both the dezincified layer and the oxide layer thicken with current.

Also shown in Fig. 12 is the dezincification factor (Z factor), eq. 6 [5]:

$$Z = \frac{(Zn/Cu)_{oxidized}}{(Zn/Cu)_{metal}} = \frac{Q_{Zn(aq)}(STW) + Q_{Zn(aq)}(CBS)}{Q_{Cu(aq)}(STW) + Q_{Cu(aq)}(CBS)}$$
(6)

From this definition, Z=1 would represent perfect congruent dissolution. Z>1 represents a preferential dissolution of Zn, the degree of which is quantified by the magnitude of Z. Fig. 12 shows clearly that the Z factor decreases rapidly with increasing current for $i_{ap} < 20 \,\mu\text{A cm}^{-2}$, and approaches Z=1.5 for $i_{ap} > 20 \,\mu\text{A cm}^{-2}$. CuZn21Si3P has a smaller Z than CuZn42 at various current values, which corroborates the ISO dezincification test result, as is shown in Fig. 1.

Also in Fig. 12, δ_{Cu} , increased linearly with increasing applied current for each alloy. This result contrasts with that of Pchelnikov [11] who reported that on an α -brass, the dezincified layer was independent of time and applied current. This result lead him to conclude that a dissolution/redeposition mechanism was

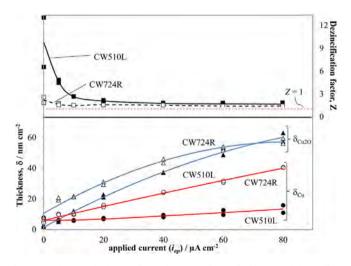


Fig. 12. Thickness calculation of Cu₂O layer and dezincified layer, and dezincification factor (*Z* factor) as a function of applied current.

 $Zn \rightarrow Zn^{2+} (aq) + 2e^{-}$

operative as the steady state thickness would require both dissolution and redeposition.

4. Kinetic analysis and Discussion

$$\mathbf{Cu} \to \mathbf{Cu}^+ (aq) + e^- \tag{8}$$

(7)

The results presented here demonstrate that the primary reactions involved in the corrosion of brass in tap water are as follows:

$$2Cu^{+}(aq) + H_{2}O \rightarrow Cu_{2}O(s) + 2H^{+}$$
(9)

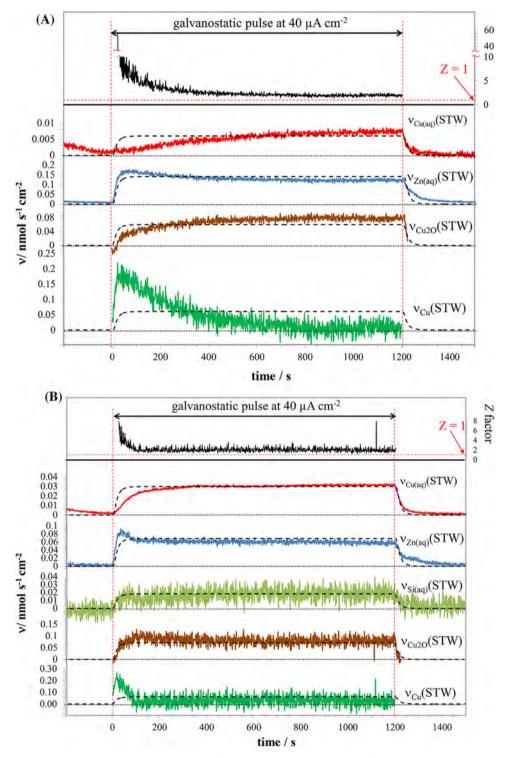


Fig. 13. Kinetic analysis of elemental dissolution, oxide film and the dezincified pure copper layer growth in STW of CuZn42 (A) and CuZn21Si3P (B) at i_{ap} = 40 μ A cm⁻². The dashed line represents the hypothetical curve for a step function after correcting for AESEC time constant.

The formation of the Cu rich dezincification layer may be attributed to one of two broad classes of mechanisms: 1) redeposition due to the oxidation of Zn with Cu^{2+} or the disproportionation of Cu_2O [1], or 2) a selective dissolution of Zn via a surface diffusion [19] or percolation mechanism [21]. Insight into the mechanism of dealloying may be gained via a time resolved kinetic analysis of the elemental dissolution and film growth.

An example, the kinetic analysis of brass dissolution in STW under a 40 μ A cm⁻² galvanostatic pulse is shown in Fig. 13. In this figure, the $v_{Cu(aq)}$, $v_{Zn(aq)}$ are the direct dissolution profiles from ICP-OES. The instantaneous growth rate of oxide film, v_{Cu_20} , and the dezincified layer, v_{Cu} , was calculated via eq. 10-11.

$$v_{Cu20} = [v_e^{-} - \sum v_{m(aq)}]/2 \tag{10}$$

$$\mathbf{v}_{Cu} = a \ v_{Zn(aq)} - v_{Cu_2O} - v_{Cu_2(aq)} \tag{11}$$

where ν_{e}^{*} is the convoluted electrical current, $\sum \nu_{m(aq)}$ is the sum of elemental dissolution rates, and α is the molar ratio of Zn/Cu in the bulk material. Also, the instantaneous dezincification factor, *Z*, as a function of time, is presented in this figure to demonstrate the instantaneous dezincification severity.

In Fig. 13, the dashed curves represent the convoluted electrical current, normalized to the steady state value of each component. If dissolution and film growth followed directly the applied current, that is to say the rate increased in an instantaneous step to the steady state, it would be expected to follow this curve. The convolution of the current accounts for the broadening of the measured result due to mixing in the flow cell.

The Zn dissolution rate increases very rapidly at the application of anodic current and actually passes through a maximum during the early stages of the experiment. In contrast, the Cu dissolution rate increases slowly only reaching steady state after several minutes. The increase of the Cu₂O film is in fairly good agreement with the convoluted current while the formation of the metallic Cu-rich dealloyed layer (dezincified zone) shows an intense peak during the early period and drops off to a near zero value.

These results are consistent with the hypothesis that, at t = 0, Zn is oxidized more readily than Cu and a certain degree of Zn depletion must occur before Cu will oxidize directly to soluble Cu (II). Initially, Cu oxidation occurs via the formation of Cu₂O. Cu dissolution increases slowly as Zn depletion occurs, reaching a steady state only when the Cu film (dezincified layer) has also obtained a steady state configuration.

The selective dissolution of Zn was observed under all experimental conditions in STW, that is to say that the release of soluble Zn species (eq. 7) occurred more rapidly than the release of soluble Cu species (eq. 8), irrespective of the Cu to Zn ratio of the brass. When an anodic current was applied, a clear preferential formation of Cu₂O on the surface was observed on both alloys, especially in the lower current region. So, in the corrosion of Cu-Zn alloys, most Cu being oxidized will be present in the form of an oxide film; Zn is oxidized into both Zn soluble species that are released into STW and relatively small amounts of insoluble oxides/hydroxides that are deposited on the surface.

Under the conditions of the AESEC system, CuZn21Si3P has a better corrosion resistance (Table 2) and dezincification resistance (Fig. 12), especially at low anodic current ($i_{ap} \le 10 \,\mu\text{A}\,\text{cm}^{-2}$). This may be attributed to the absence of the high zinc containing β ' phase.

Nevertheless, the anodic dissolution transients of Cu and Zn in STW for the two alloys differ markedly from each other. This may likewise be attributed to the differences in their metallurgical phases. It is well known that the β ' phase in brass is more sensitive

to dezincification, due to the higher solubility of Zn in solid solution. The dezincification of α , β '-brass initiates firstly on the β ' phase [50], and propagates along the crystal boundary or dislocations [2,51], since the β ' phase has a corrosion potential of 180 mV more negative than the α phase [52]. However, the SEM observation didn't show a clear composition contrast on CuZn42 that was due to the differentiation of dissolution rate among α and β ' phase. On the contrary, the contrast may be observed on CuZn21Si3P, which is not only due to the preferential distribution of Cu₂O particles, the chemical composition of the underlying phases must have changed significantly. Seuss et al. [1] reported that in the exposure of CuZnSi3P to aggressive tap water, κ phase shows a corrosion potential of more than 50 mV more negative than α phase, γ phase has a value of 100 mV more negative than κ phase. This means that more severe dissolution occurred on some metallurgical phases. However, the average corrosion rate of CuZn21Si3P was still lower than CuZn42. This can be explained by a relatively small proportion of less noble phases in the CuZnSi3P matrix. It is reasonable to conclude that the difference in the dezincification performance was a direct result of the metallurgical phase difference. The γ phase, even the κ phase may contribute to the release of Cu²⁺ into tap water, also in turn promoting the formation of Cu oxides.

The kinetic analysis shown in Fig. 13 demonstrates that the anodic dissolution of brass comprises two stages: a first stage where a growth peak of the dezincified layer can be found during the initial period of the galvanostatic pulse; and a second stage where the growth peak decreases to a very low rate, indicating a simultaneous dissolution of Cu and Zn or at least a less severe preferential dissolution of Zn, since the Z factor in this stage is close to 2 (Fig. 13). Among the two alloys, obviously CuZn42 shows a more intense growth of the dezincified layer consistent with the accelerated test results of Fig. 1.

The two-stage phenomenon found in the anodic dissolution of brass seems to support the dissolution-redeposition mechanism [2,5,10,11]. However, considering the complex metallurgical structure of the alloys investigated, the non-clarity as to the oxidation process of Cu to Cu₂O and Cu²⁺ species, and the possibility of galvanic corrosion among different metallurgical phases, a detailed conclusion regarding the mechanism is still yet to be made. Further work with pure phase samples of α brass and β ' brass is in progress to address these questions.

5. Conclusions

In this work, the dezincification kinetics of two commercial brass samples, CuZn42 and CuZn21Si3P, were investigated.

- 1. The main products of the anodic dissolution of brass in synthetic tap water (STW) were soluble Cu(II) and Zn(II) species, and a solid Cu₂O film. A Zn depleted metallic Cu film was formed due to the selective dissolution (dezincification) of Zn.
- 2. The partial dissolution rates of Cu and Zn as a function of time throughout the exposure of brass to a synthetic tap water solution were established. Zn dissolution was significantly enhanced during the first stages of the exposure indicative of a dezincification reaction.
- The rates of formation of the Cu₂O layer and the Zn depleted metallic Cu layer were determined as a function of time via a mass/charge balance.
- 4. Cu oxidation during the early stages of the galvanostatic pulse formed Cu₂O; the rate of soluble Cu(II) formation increased slowly with time.
- 5. The dezincified layer grew rapidly during the early stages but slowed to almost zero at longer times as the rate of Cu dissolution increased.

6. The overall kinetic picture was similar for the two brass samples, however the CuZn42, a duplex (α , β '-brass) showed a significantly more intense dezincification rate which was attributed to the presence of the β ' phase with high Zn content.

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